

# FODM121 Series, FODM124, FODM2701 Series, FODM2705 4-Pin Full Pitch Mini-Flat Package Transistor Output Optocouplers

## Features

- >5mm creepage/clearance
- Compact 4-pin surface mount package (2.4mm maximum standoff height)
- Current Transfer Ratio in selected groups  
DC Input:  

FODM121: 50–600%	FODM2701: 50–300%
FODM121A: 100–300%	FODM2701A: 150–300%
FODM121B: 50–150%	FODM2701B: 80–160%
FODM121C: 100–200%	FODM124: 100% MIN
FODM121D: 50–100%	
FODM121E: 150–300%	
FODM121F: 100–600%	
FODM121G: 200–400%	
- AC Input:  
FODM2705: 50–300%
- Available in tape and reel quantities of 500 and 2500
- Applicable to Infrared Ray reflow (260°C max, 10 seconds)
- C-UL, UL and VDE\* certifications

\*option 'V' required

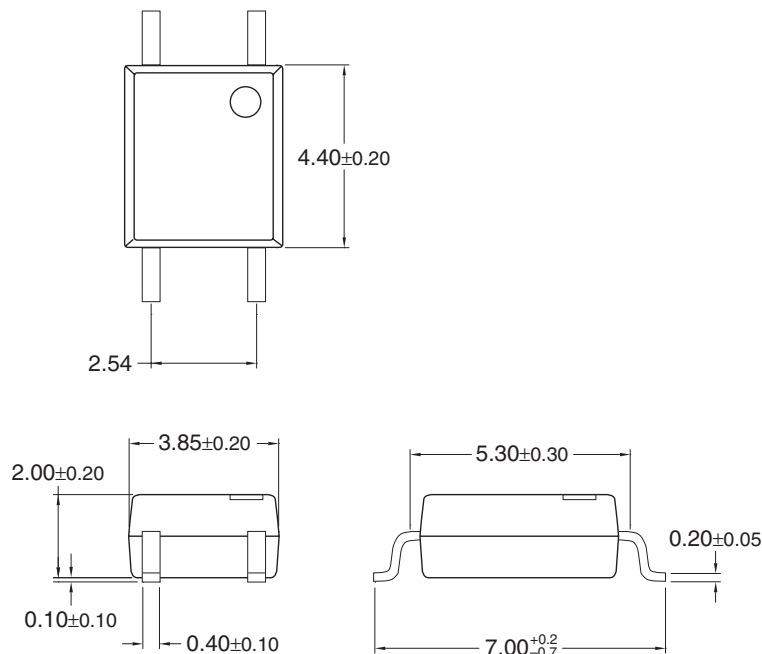
## Applications

- Digital logic inputs
- Microprocessor inputs
- Power supply monitor
- Twisted pair line receiver
- Telephone line receiver

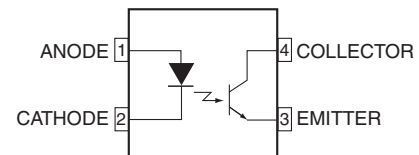
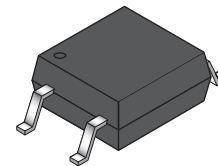
## Description

The FODM124, FODM121, and FODM2701 series consists of a gallium arsenide infrared emitting diode driving a phototransistor in a compact 4-pin mini-flat package. The lead pitch is 2.54 mm. The FODM2705 series consists of two gallium arsenide infrared emitting diodes connected in inverse parallel for AC operation.

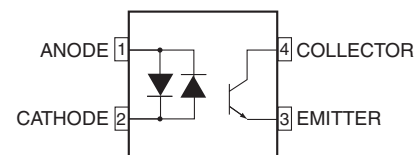
## Package Dimensions



**Note:**  
All dimensions are in millimeters.



**Equivalent Circuit**  
**FODM121, FODM124, FODM2701**



**Equivalent Circuit**  
**FODM2705**

### Absolute Maximum Ratings ( $T_A = 25^\circ\text{C}$ unless otherwise specified)

Symbol	Parameter	Value	Units	
<b>TOTAL PACKAGE</b>				
$T_{STG}$	Storage Temperature	-40 to +125	$^\circ\text{C}$	
$T_{OPR}$	Operating Temperature	-40 to +110	$^\circ\text{C}$	
<b>EMITTER</b>				
$I_F$ (avg)	Continuous Forward Current	50	mA	
$I_F$ (pk)	Peak Forward Current (1 $\mu\text{s}$ pulse, 300 pps.)	1	A	
$V_R$	Reverse Input Voltage	6	V	
$P_D$	Power Dissipation Derate linearly (above $25^\circ\text{C}$ )	70	mW	
		0.65	mW/ $^\circ\text{C}$	
<b>DETECTOR</b>				
	Continuous Collector Current	80	mA	
$P_D$	Power Dissipation Derate linearly (above $25^\circ\text{C}$ )	150	mW	
		2.0	mW/ $^\circ\text{C}$	
$V_{CEO}$	Collector-Emitter Voltage	FODM2701 Series, FODM2705	40	V
		FODM121 Series, FODM124	80	
$V_{ECO}$	Emitter-Collector Voltage	7	V	

### Electrical Characteristics ( $T_A = 25^\circ\text{C}$ )

#### Individual Component Characteristics

Symbol	Parameter	Test Conditions	Device	Min.	Typ.*	Max.	Unit
<b>EMITTER</b>							
$V_F$	Forward Voltage	$I_F = 10\text{mA}$	FODM121 Series FODM124	1.0		1.3	V
		$I_F = 5\text{mA}$	FODM2701 Series			1.4	
		$I_F = \pm 5\text{mA}$	FODM2705				
$I_R$	Reverse Current	$V_R = 5\text{V}$	FODM2701 Series			5	$\mu\text{A}$
			FODM121 Series				
			FODM124				
<b>DETECTOR</b>							
$BV_{CEO}$	Breakdown Voltage Collector to Emitter	$I_C = 1\text{mA}, I_F = 0$	FODM121 Series FODM124	80			V
			FODM2701 Series FODM2705	40			
$BV_{ECO}$	Emitter to Collector	$I_E = 100\mu\text{A}, I_F = 0$	All	7		-	V
$I_{CEO}$	Collector Dark Current	$V_{CE} = 40\text{V}, I_F = 0$	All			100	nA
$C_{CE}$	Capacitance	$V_{CE} = 0\text{V}, f = 1\text{MHz}$	All		10		pF

### Transfer Characteristics ( $T_A = 25^\circ\text{C}$ )

Symbol	Characteristic	Test Conditions	Device	Min.	Typ.**	Max.	Unit
CTR	DC Current Transfer Ratio	$I_F = \pm 5\text{mA}$ , $V_{CE} = 5\text{V}$	FODM2705	50		300	%
			FODM2701	50		300	
			FODM2701A	150		300	
			FODM2701B	80		160	
		$I_F = 5\text{mA}$ , $V_{CE} = 5\text{V}$	FODM121	50		600	
			FODM121A	100		300	
			FODM121B	50		150	
			FODM121C	100		200	
			FODM121D	50		100	
			FODM121E	150		300	
			FODM121F	100		600	
			FODM121G	200		400	
		$I_F = 1\text{mA}$ , $V_{CE} = 0.4\text{V}$	FODM121F	30			
$I_F = 1\text{mA}$ , $V_{CE} = 0.5\text{V}$	FODM124	100		1200			
$I_F = 0.5\text{mA}$ , $V_{CE} = 1.5\text{V}$	FODM124	50					
	CTR Symmetry	$I_F = \pm 5\text{mA}$ , $V_{CE} = 5\text{V}$	FODM2705	0.3		3.0	
$V_{CE(SAT)}$	Saturation Voltage	$I_F = \pm 10\text{mA}$ , $I_C = 2\text{mA}$	FODM2705			0.3	V
			FODM2701			0.3	
			FODM2701A			0.3	
			FODM2701B			0.3	
		$I_F = 8\text{mA}$ , $I_C = 2.4\text{mA}$	FODM121			0.4	
			FODM121A			0.4	
			FODM121B			0.4	
			FODM121C			0.4	
			FODM121D			0.4	
			FODM121E			0.4	
			FODM121F			0.4	
			FODM121G			0.4	
		$I_F = 1\text{mA}$ , $I_C = 0.2\text{mA}$	FODM121F			0.4	
$I_F = 1\text{mA}$ , $I_C = 0.5\text{mA}$	FODM124			0.4			
$t_r$	Rise Time (Non-Saturated)	$I_C = 2\text{mA}$ , $V_{CE} = 5\text{V}$ , $R_L = 100\Omega$	All		3		$\mu\text{s}$
$t_f$	Fall Time (Non-Saturated)	$I_C = 2\text{mA}$ , $V_{CE} = 5\text{V}$ , $R_L = 100\Omega$	All		3		$\mu\text{s}$

### Isolation Characteristics

Characteristic	Test Conditions	Symbol	Device	Min.	Typ.*	Max.	Unit
Steady State Isolation Voltage <sup>(1)</sup>	1 Minute	$V_{ISO}$	All	3750			VRMS

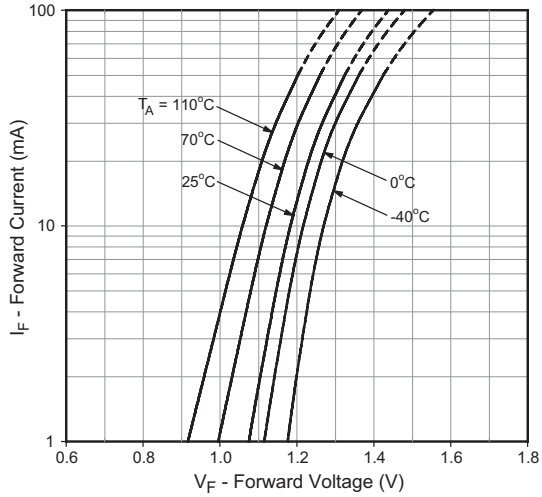
\*All typicals at  $T_A = 25^\circ\text{C}$

**Note:**

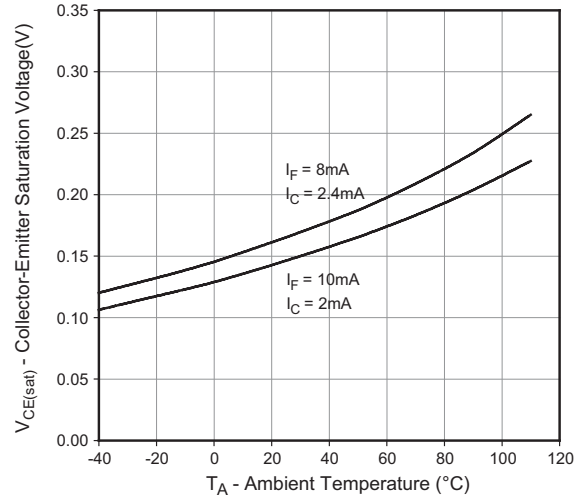
1. Steady state isolation voltage,  $V_{ISO}$ , is an internal device dielectric breakdown rating. For this test, pins 1 and 2 are common, and pins 3 and 4 are common.

## Typical Performance Curves

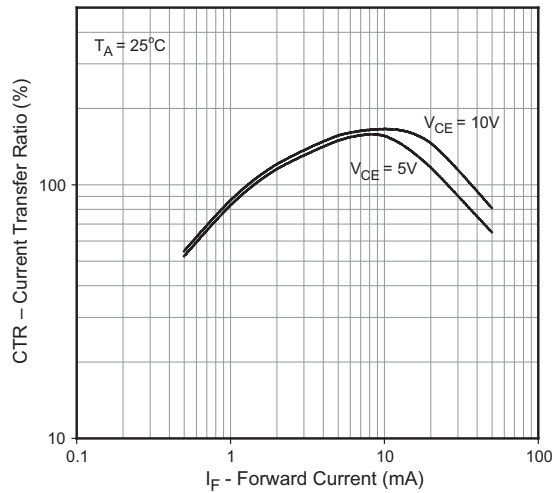
**Fig. 1 Forward Current vs. Forward Voltage**



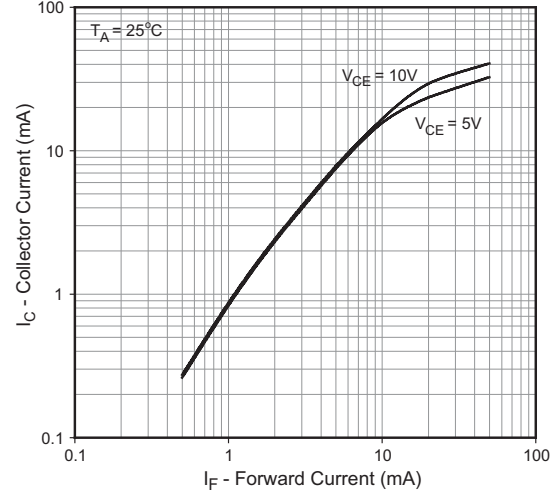
**Fig. 2 Collector-Emitter Saturation Voltage vs. Ambient Temperature (FODM121/2701/2705)**



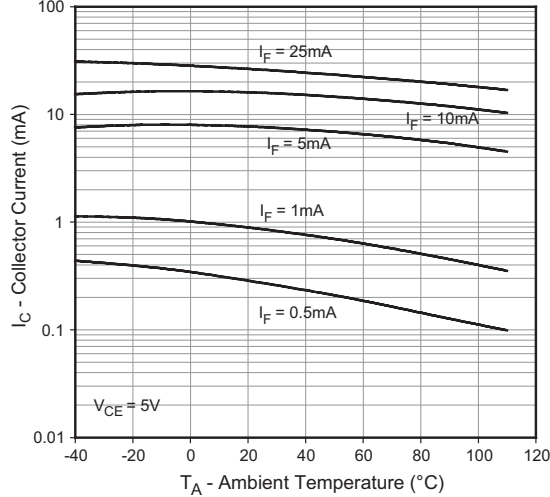
**Fig. 3 Current Transfer Ratio vs. Forward Current (FODM121/2701/2705)**



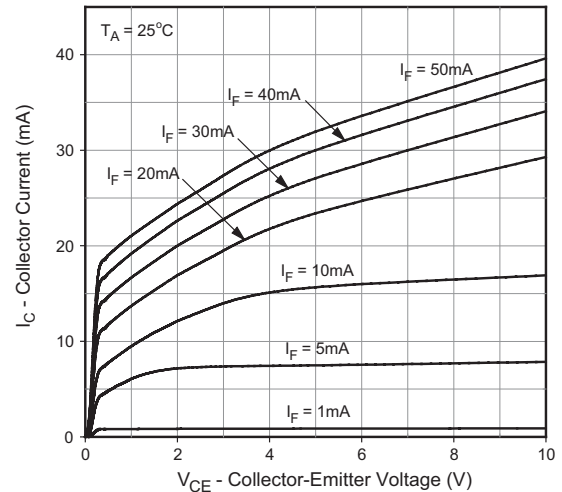
**Fig. 4 Collector Current vs. Forward Current (FODM121/2701/2705)**



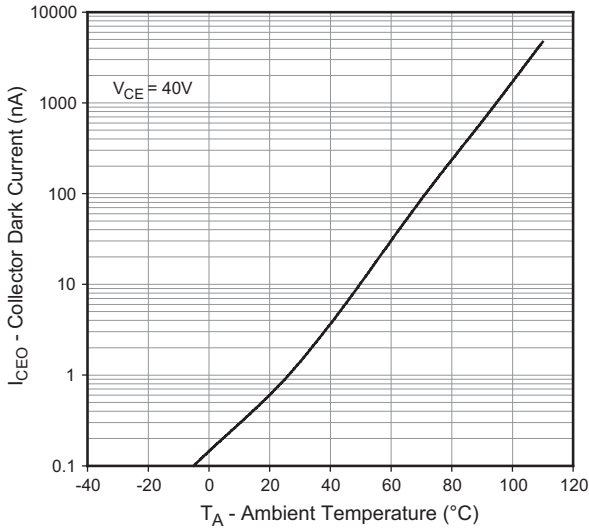
**Fig. 5 Collector Current vs. Ambient Temperature (FODM121/2701/2705)**



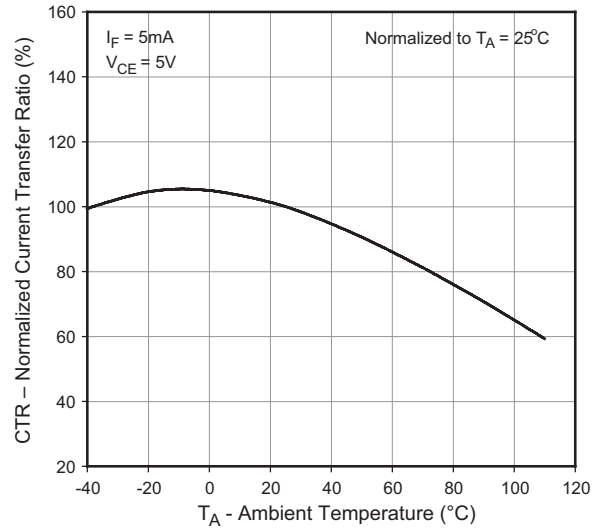
**Fig. 6 Collector Current vs. Collector-Emitter Voltage (FODM121/2701/2705)**



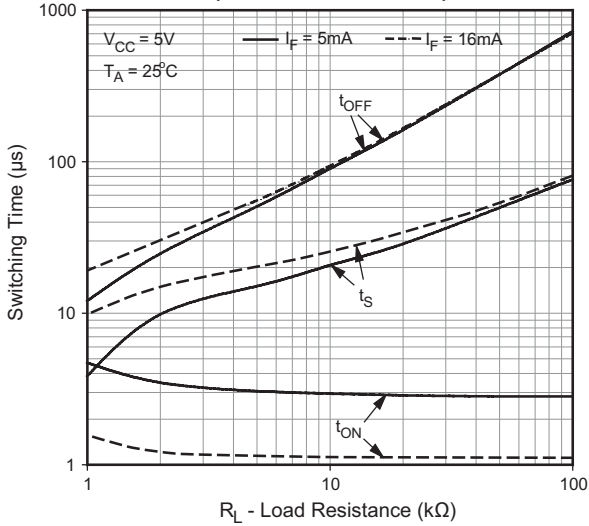
**Fig 7. Collector Dark Current vs. Ambient Temperature (FODM121/2701/2705)**



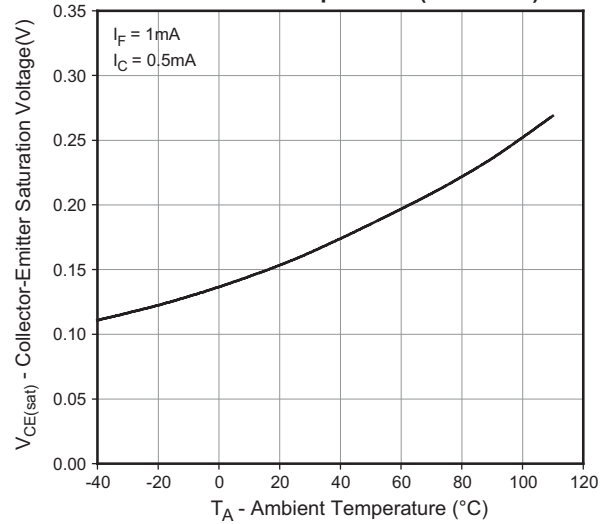
**Fig 8 Normalized Current Transfer Ratio vs. Ambient Temperature (FODM121/2701/2705)**



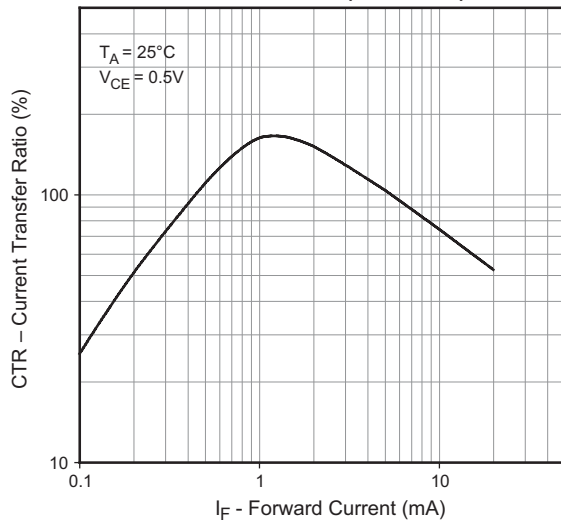
**Fig. 9 Switching Time vs. Load Resistance (FODM121/2701/2705)**



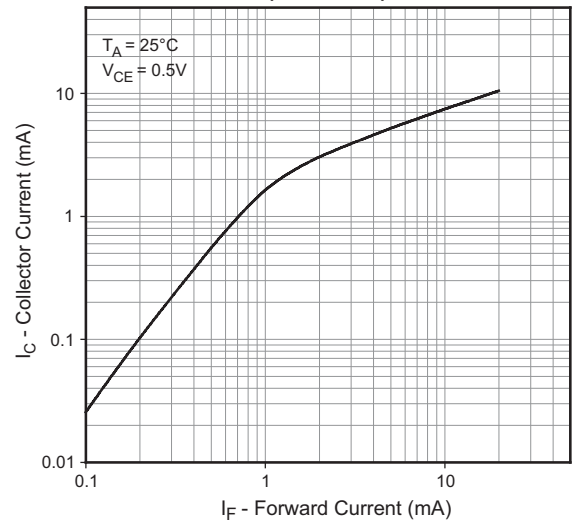
**Fig. 10 Collector-Emitter Saturation Voltage vs. Ambient Temperature (FODM124)**



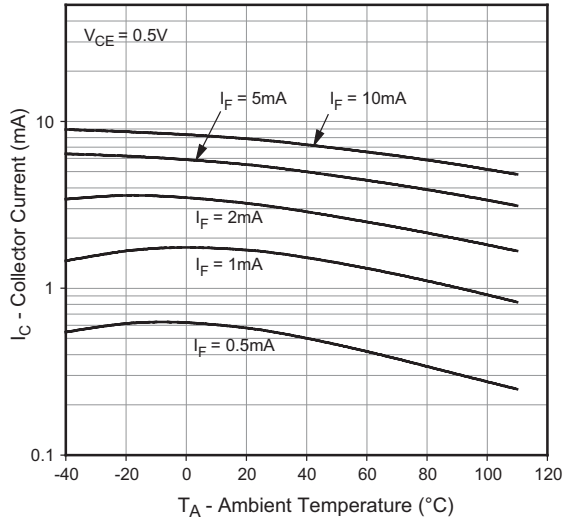
**Fig. 11 Current Transfer Ratio vs. Forward Current (FODM124)**



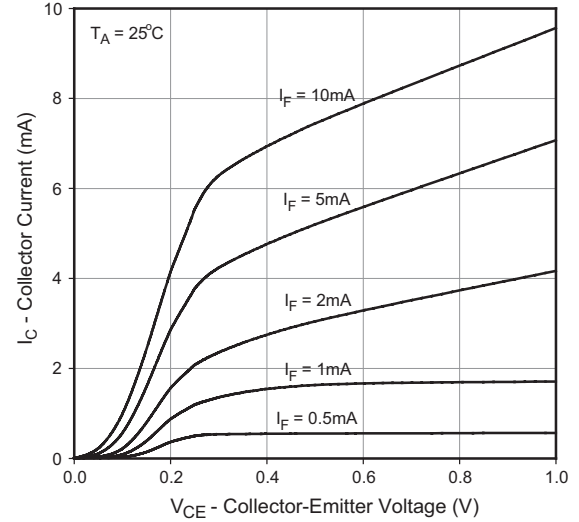
**Fig 12. Collector Current vs. Forward Current (FODM124)**



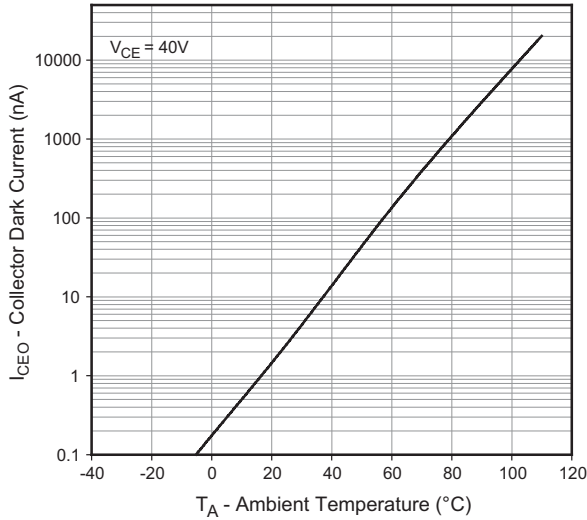
**Fig 13. Collector Current vs. Ambient Temperature (FODM124)**



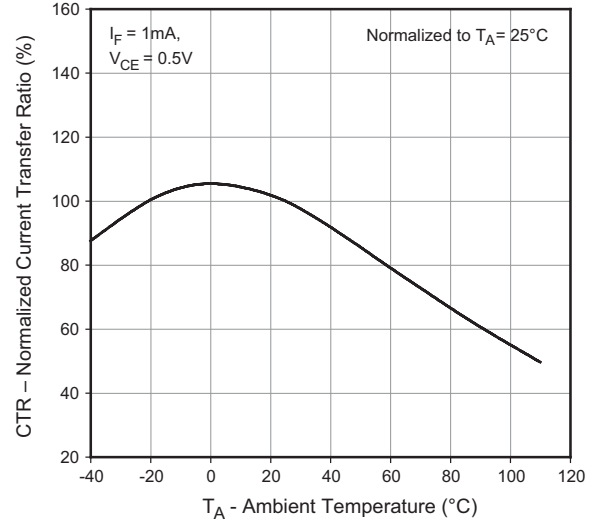
**Fig 14 Collector Current vs. Collector-Emitter Voltage (FODM124)**



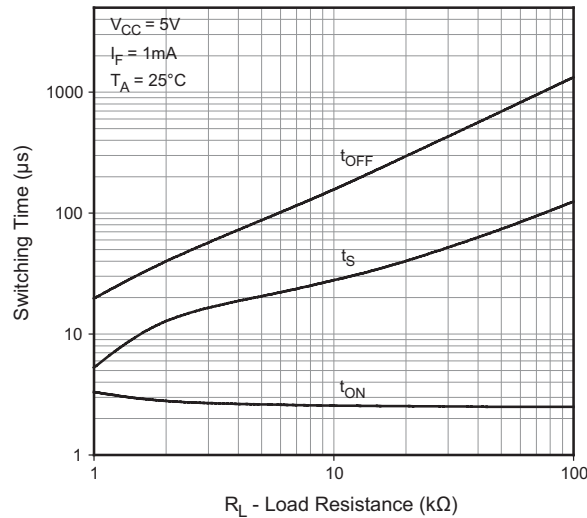
**Fig 15 Collector Dark Current vs. Ambient Temperature (FODM124)**



**Fig 16 Normalized Current Transfer Ratio vs. Ambient Temperature (FODM124)**



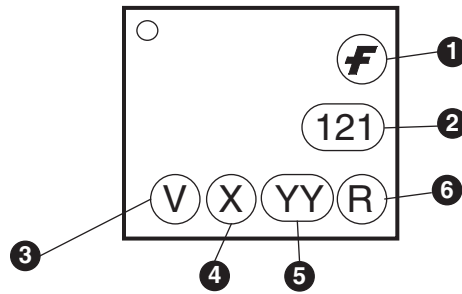
**Fig 17 Switching Time vs. Load Resistance (FODM124)**



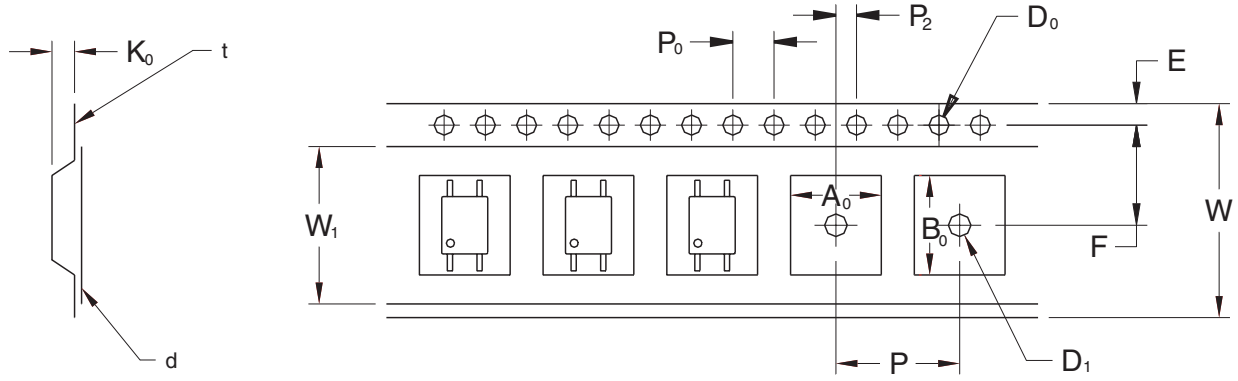
## Ordering Information

Option	Description
V	VDE Approved
R1	Tape and Reel (500 units)
R2	Tape and Reel (2500 units)
R1V	Tape and Reel (500 units) and VDE Approved
R2V	Tape and Reel (2500 units) and VDE Approved

## Marking Information



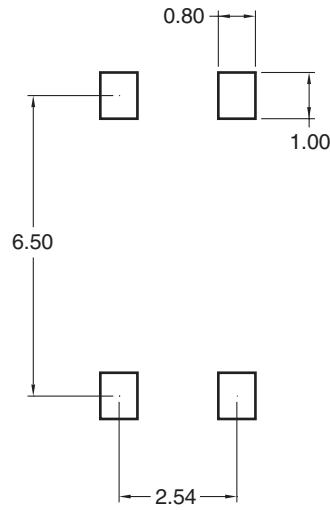
Definitions	
1	Fairchild logo
2	Device number
3	VDE mark (Note: Only appears on parts ordered with VDE option – See order entry table)
4	One digit year code
5	Two digit work week ranging from '01' to '53'
6	Assembly package code



Description		Symbol	2.54 Pitch Dimensions (mm)
Tape Width		W	12.00±0.4
Tape Thickness		t	0.35±0.02
Sprocket Hole Pitch		P <sub>0</sub>	4.00±0.20
Sprocket Hole Dia.		D <sub>0</sub>	1.55±0.20
Sprocket Hole Location		E	1.75±0.20
Pocket Location		F	5.50±0.20
		P <sub>2</sub>	2.00±0.20
Pocket Pitch		P	8.00±0.20
Pocket Dimension		A <sub>0</sub>	4.75±0.20
		B <sub>0</sub>	7.30±0.20
		K <sub>0</sub>	2.30±0.20
Pocket Hole Dia.		D <sub>1</sub>	1.55±0.20
Cover Tape Width		W <sub>1</sub>	9.20
Cover Tape Thickness		d	0.065±0.02
Max. Component Rotation or Tilt			20° max
Devices Per Reel	R1		500
	R2		2500
Reel Diameter	R1		178 mm (7")
	R2		330 mm (13")



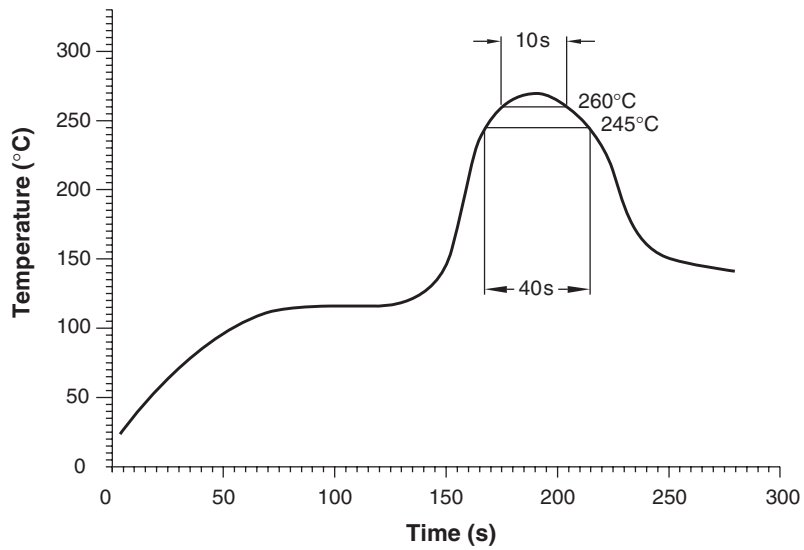
### Footprint Drawing for PCB Layout



**Note:**  
All dimensions are in mm.

### Recommended Infrared Reflow Soldering Profile

- Peak reflow temperature: 260°C (package surface temperature)
- Time of temperature higher than 245°C: 40 seconds or less
- Number of reflows: 3



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FASTr™	MicroPak™	QT Optoelectronics™	TinyPWM™	
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- A critical component is any component of a life support device or system whose failure to perform can be reasonably expected to cause the failure of the life support device or system, or to affect its safety or effectiveness.

### PRODUCT STATUS DEFINITIONS

#### Definition of Terms

Datasheet Identification	Product Status	Definition
Advance Information	Formative or In Design	This datasheet contains the design specifications for product development. Specifications may change in any manner without notice.
Preliminary	First Production	This datasheet contains preliminary data, and supplementary data will be published at a later date. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
No Identification Needed	Full Production	This datasheet contains final specifications. Fairchild Semiconductor reserves the right to make changes at any time without notice to improve design.
Obsolete	Not In Production	This datasheet contains specifications on a product that has been discontinued by Fairchild semiconductor. The datasheet is printed for reference information only.

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